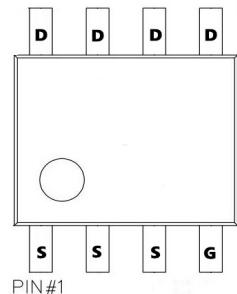
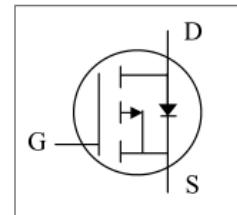


Description

The LM8S14P03 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



General Features

$V_{DS} = 30V$ $I_D = 14A$

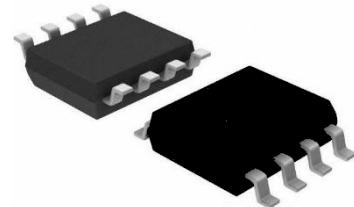
$R_{DS(ON)} < 8.7m\Omega$ @ $V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply



Package Marking and Ordering Information

| Product ID | Pack | Marking | Qty(PCS) |
|------------|-------|------------------|----------|
| LM8S14P03 | SOP-8 | AP4409A XXX YYYY | 3000 |

Absolute Maximum Ratings ($T_c=25^\circ C$ unless otherwise noted)

| Symbol | Parameter | Rating | Units |
|----------------------|---|------------|-------|
| V_{DS} | Drain-Source Voltage | -30 | V |
| V_{GS} | Gate-Source Voltage | ± 20 | V |
| $I_D@T_A=25^\circ C$ | Continuous Drain Current, $V_{GS} @ -10V^1$ | -14 | A |
| $I_D@T_A=70^\circ C$ | Continuous Drain Current, $V_{GS} @ -10V^1$ | -11 | A |
| I_{DM} | Pulsed Drain Current ² | -56 | A |
| EAS | Single Pulse Avalanche Energy ³ | 151 | mJ |
| I_{AS} | Avalanche Current | -55 | A |
| $P_D@T_A=25^\circ C$ | Total Power Dissipation ⁴ | 1.5 | W |
| T_{STG} | Storage Temperature Range | -55 to 150 | °C |
| T_J | Operating Junction Temperature Range | -55 to 150 | °C |
| $R_{\theta JA}$ | Thermal Resistance Junction-Ambient ¹ ($t \leq 10s$) | 40 | °C/W |
| | Thermal Resistance Junction-Ambient ¹ | 75 | °C/W |
| $R_{\theta JC}$ | Thermal Resistance Junction-Case ¹ | 24 | °C/W |

Electrical Characteristics ($T_J=25^\circ\text{C}$, unless otherwise noted)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|--|--|--|------|--------|-----------|----------------------------|
| BV_{DSS} | Drain-Source Breakdown Voltage | $V_{\text{GS}}=0\text{V}$, $I_D=-250\mu\text{A}$ | -30 | --- | --- | V |
| $\Delta \text{BV}_{\text{DSS}}/\Delta T_J$ | BV_{DSS} Temperature Coefficient | Reference to 25°C , $I_D=-1\text{mA}$ | --- | -0.018 | --- | $\text{V}/^\circ\text{C}$ |
| $R_{\text{DS(ON)}}$ | Static Drain-Source On-Resistance ² | $V_{\text{GS}}=-10\text{V}$, $I_D=-12\text{A}$ | --- | --- | 8.7 | $\text{m}\Omega$ |
| | | $V_{\text{GS}}=-4.5\text{V}$, $I_D=-10\text{A}$ | --- | --- | 13.5 | |
| $V_{\text{GS(th)}}$ | Gate Threshold Voltage | $V_{\text{GS}}=V_{\text{DS}}$, $I_D=-250\mu\text{A}$ | -1.2 | --- | -2.5 | V |
| $\Delta V_{\text{GS(th)}}$ | $V_{\text{GS(th)}}$ Temperature Coefficient | | --- | 5.04 | --- | $\text{mV}/^\circ\text{C}$ |
| I_{DSS} | Drain-Source Leakage Current | $V_{\text{DS}}=-24\text{V}$, $V_{\text{GS}}=0\text{V}$, $T_J=25^\circ\text{C}$ | --- | --- | -1 | uA |
| | | $V_{\text{DS}}=-24\text{V}$, $V_{\text{GS}}=0\text{V}$, $T_J=55^\circ\text{C}$ | --- | --- | -5 | |
| I_{GSS} | Gate-Source Leakage Current | $V_{\text{GS}}=\pm 20\text{V}$, $V_{\text{DS}}=0\text{V}$ | --- | --- | ± 100 | nA |
| g_{fs} | Forward Transconductance | $V_{\text{DS}}=-5\text{V}$, $I_D=-12\text{A}$ | --- | 25 | --- | S |
| Q_g | Total Gate Charge (-4.5V) | $V_{\text{DS}}=-15\text{V}$, $V_{\text{GS}}=-4.5\text{V}$, $I_D=-12\text{A}$ | --- | 30 | --- | nC |
| Q_{gs} | Gate-Source Charge | | --- | 10 | --- | |
| Q_{gd} | Gate-Drain Charge | | --- | 10.4 | --- | |
| $T_{\text{d(on)}}$ | Turn-On Delay Time | $V_{\text{DD}}=-15\text{V}$, $V_{\text{GS}}=-10\text{V}$, $R_G=3.3\text{k}\Omega$, $I_D=-1\text{A}$ | --- | 9.4 | --- | ns |
| T_r | Rise Time | | --- | 10.2 | --- | |
| $T_{\text{d(off)}}$ | Turn-Off Delay Time | | --- | 117 | --- | |
| T_f | Fall Time | | --- | 24 | --- | |
| C_{iss} | Input Capacitance | $V_{\text{DS}}=-15\text{V}$, $V_{\text{GS}}=0\text{V}$, $f=1\text{MHz}$ | --- | 3448 | --- | pF |
| C_{oss} | Output Capacitance | | --- | 508 | --- | |
| C_{rss} | Reverse Transfer Capacitance | | --- | 421 | --- | |
| I_s | Continuous Source Current ^{1,5} | $V_G=V_D=0\text{V}$, Force Current | --- | --- | -14 | A |
| I_{SM} | Pulsed Source Current ^{2,5} | | --- | --- | -56 | A |
| V_{SD} | Diode Forward Voltage ² | $V_{\text{GS}}=0\text{V}$, $I_s=-1\text{A}$, $T_J=25^\circ\text{C}$ | --- | --- | -1.2 | V |
| t_{rr} | Reverse Recovery Time | $I_F=-10\text{A}$, $dI/dt=100\text{A}/\mu\text{s}$, $T_J=25^\circ\text{C}$ | --- | 19.4 | --- | nS |
| Q_{rr} | Reverse Recovery Charge | $T_J=25^\circ\text{C}$ | --- | 9.1 | --- | nC |

Note :

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- 3.The EAS data shows Max. rating . The test condition is $V_{\text{DD}}=-25\text{V}$, $V_{\text{GS}}=-10\text{V}$, $L=0.1\text{mH}$, $I_{\text{AS}}=-55\text{A}$
- 4.The power dissipation is limited by 150°C junction temperature
- 5.The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.

Typical Characteristics

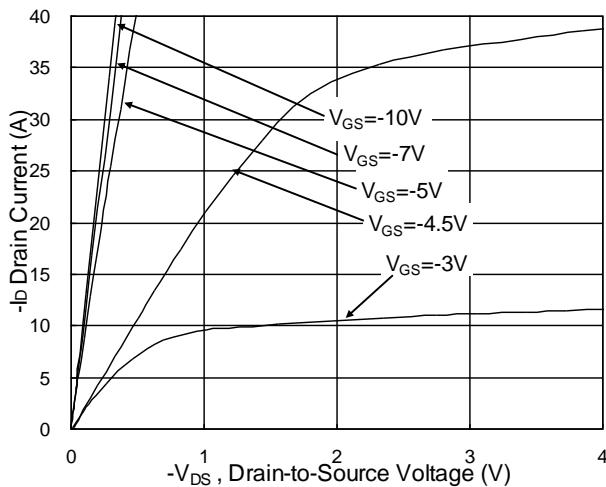


Fig.1 Typical Output Characteristics

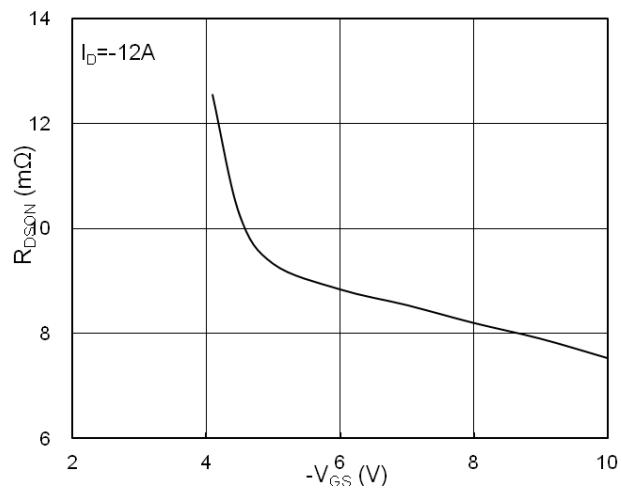


Fig.2 On-Resistance v.s Gate-Source

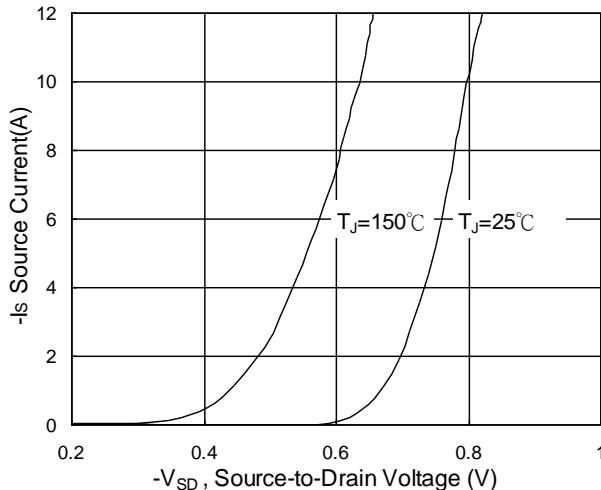


Fig.3 Forward Characteristics Of Reverse

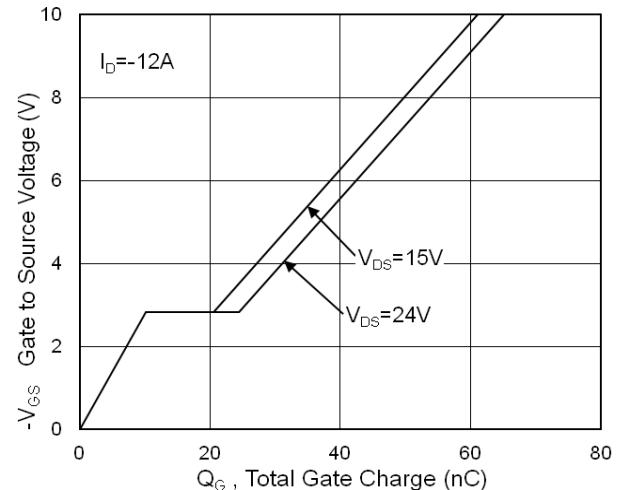


Fig.4 Gate-Charge Characteristics

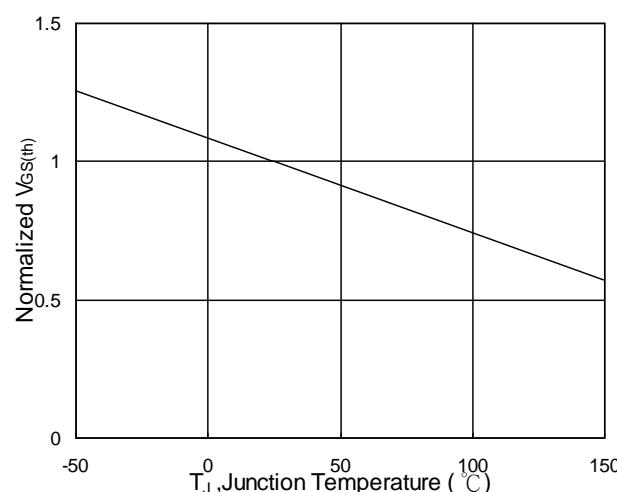


Fig.5 Normalized $V_{GS(th)}$ vs. T_J

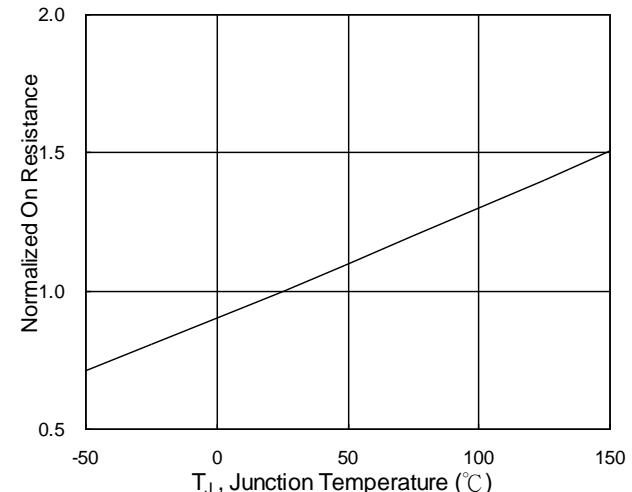


Fig.6 Normalized $R_{DS(on)}$ vs. T_J

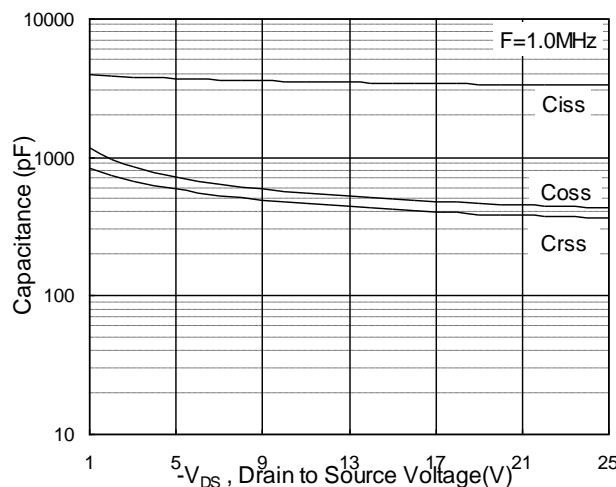


Fig.7 Capacitance

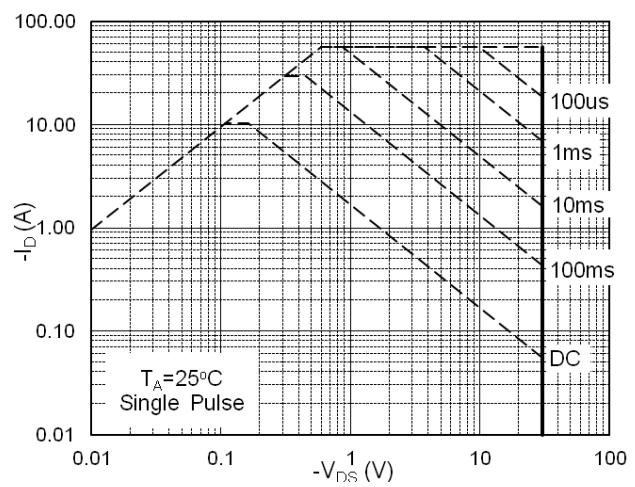


Fig.8 Safe Operating Area

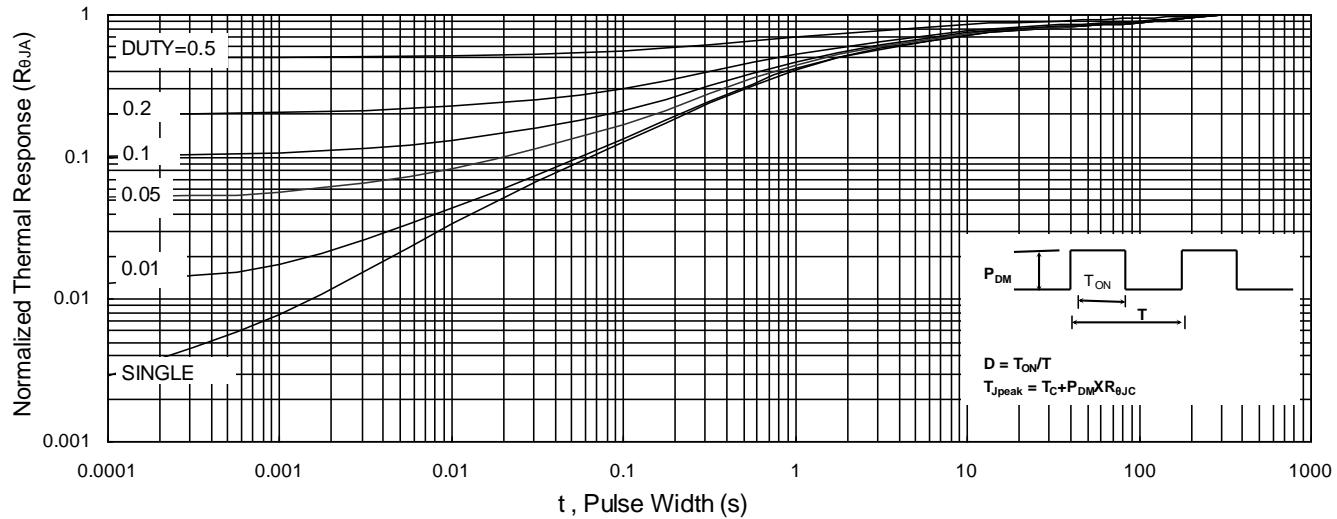


Fig.9 Normalized Maximum Transient Thermal Impedance

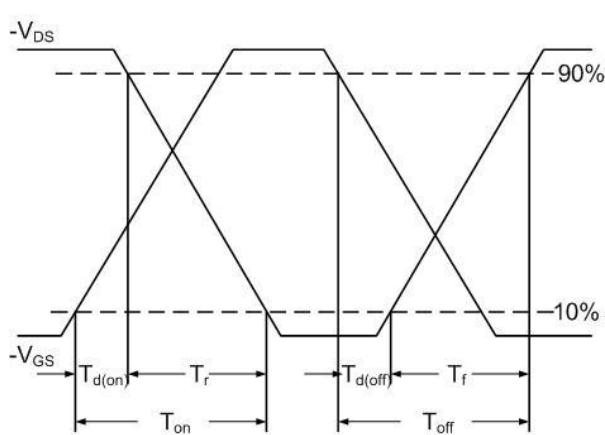


Fig.10 Switching Time Waveform

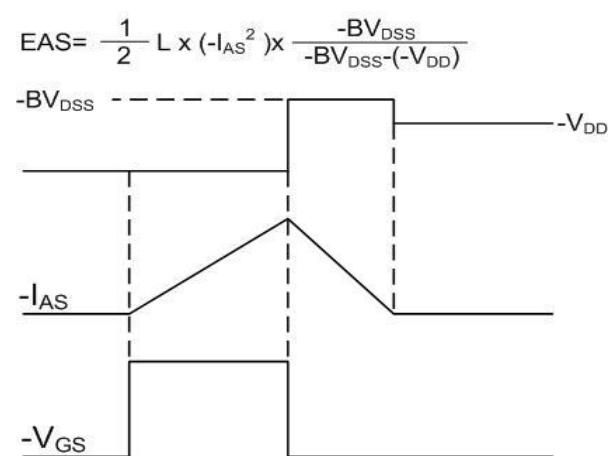
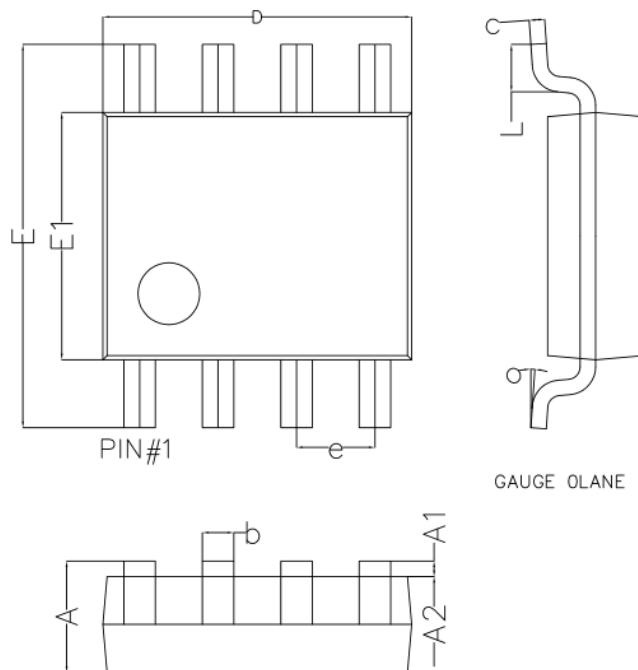


Fig.11 Unclamped Inductive Switching Waveform

SOP8 Package outline


| Symbol | Dim in mm | | |
|--------|-------------|-------|--------|
| | Min | Nor | Max |
| A | 1.350 | 1.550 | 1.750 |
| A1 | 0.100 | 0.175 | 0.250 |
| A2 | 1.350 | 1.450 | 1.550 |
| b | 0.330 | 0.420 | 0.510 |
| c | 0.170 | 0.210 | 0.250 |
| D | 4.800 | 4.900 | 5.000 |
| e | 1.270 (BSC) | | |
| E | 5.800 | 6.000 | 6.200 |
| E1 | 3.800 | 3.900 | 4.000 |
| L | 0.400 | 0.835 | 1.2700 |
| o | 0° | 4° | 8° |

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